

Data sheet acquired from Harris Semiconductor SCHS240A

September 1998 - Revised May 2000

8-Bit Serial-In/Parallel-Out Shift Register

Features

- · Buffered Inputs
- Typical Propagation Delay
 - 6ns at $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 50pF$
- Exceeds 2kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-Resistant CMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
 - Fanout to 15 FAST™ ICs
 - Drives 50 Ω Transmission Lines

Description

The 'AC164 and 'ACT164 are 8-bit serial-in/parallel-out shift registers with asynchronous reset that utilize Advanced CMOS Logic technology. Data is shifted on the positive edge of the clock (CP). A LOW on the Master Reset ($\overline{\text{MR}}$) pin resets the shift register and all outputs go to the LOW state regardless of the input conditions. Two Serial Data inputs (DS1 and DS2) are provided; either one can be used as a Data Enable control.

Ordering Information

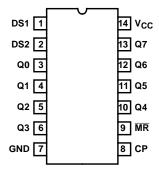
PART NUMBER	TEMP. RANGE (^O C)	PACKAGE
CD54AC164F3A	-55 to 125	14 Ld CERDIP
CD74AC164E	-55 to 125	14 Ld PDIP
CD74AC164M	-55 to 125	14 Ld SOIC
CD54ACT164F3A	-55 to 125	14 Ld CERDIP
CD74ACT164E	-55 to 125	14 Ld PDIP
CD74ACT164M	-55 to 125	14 Ld SOIC

NOTES:

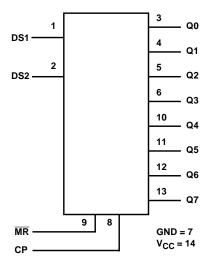
- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Wafer and die for this part number is available which meets all electrical specifications. Please contact your local TI sales office or customer service for ordering information.

Pinout

CD54AC164, CD54ACT164 (CERDIP) CD74AC164, CD74ACT164 (PDIP, SOIC) TOP VIEW



Functional Diagram



MODE SELECT - TRUTH TABLE

		INP	OUTPUTS			
OPERATING MODE	MR	СР	DS1	DS2	Q0	Q1 - Q7
RESET (CLEAR)	L	Х	Х	Х	L	L-L
SHIFT	Н	1	I	I	L	q0 - q6
	Н	1	I	h	L	q0 - q6
	Н	1	h	I	L	q0 - q6
	Н	1	h	h	Н	q0 - q6

H = HIGH voltage level steady state.

L = LOW voltage level steady state.

h = HIGH voltage level one setup time prior to the LOW-to_HIGH clock transition.

I = LOW voltage level one setup time prior to the LOW-to-HIGH clock transition.

X = Don't care.

q = Lowercase letters indicate the state of the referenced output prior to the LOW-to-HIGH clock transition. \uparrow = LOW-to-HIGH clock transition.

Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 6V
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$
DC V _{CC} or Ground Current, I _{CC or} I _{GND} (Note 3) \pm 100mA

Thermal Information

θ_{JA} (oC/W)
90
175
150 ^o C
65°C to 150°C
300°C

Operating Conditions

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 3. For up to 4 outputs per device, add $\pm 25 \text{mA}$ for each additional output.
- 4. Unless otherwise specified, all voltages are referenced to ground.
- 5. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

		I	TEST NDITIONS V _{CC}		25	oc.		C TO °C		C TO 5°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES											
High Level Input Voltage	V _{IH}	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V _{IL}	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

DC Electrical Specifications (Continued)

		TEST CONDITIONS		v _{cc}	25°C			C TO		C TO 5°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(v)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output Voltage	V_{OL}	V _{IH} or V _{IL}	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	lį	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Quiescent Supply Current MSI	I _{CC}	V _{CC} or GND	0	5.5	-	8	-	80	-	160	μА
ACT TYPES											
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V_{OL}	V _{IH} or V _{IL}	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	l _l	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Quiescent Supply Current MSI	Icc	V _{CC} or GND	0	5.5	-	8	-	80	-	160	μΑ
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	Δl _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

NOTES:

- 6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- 7. Test verifies a minimum 50Ω transmission-line-drive capability at $85^{o}C$, 75Ω at $125^{o}C$.

ACT Input Load Table

INPUT	UNIT LOAD
DS1, DS2	0.5
MR	0.74
СР	0.71

NOTE: Unit load is Δl_{CC} limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25 $^{\rm O}C.$

Prerequisite For Switching Function

			-40°C	ГО 85°C	-55°C T		
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	UNITS
AC TYPES						•	
Max. Clock Frequency	f _{MAX}	1.5	7	-	6	-	MHz
		3.3 (Note 9)	62	-	54	-	MHz
		5 (Note 10)	86	-	75	-	MHz
MR Pulse Width	t _W	1.5	49	-	56	-	ns
		3.3	5.5	-	6.3	-	ns
		5	3.9	-	4.5	-	ns
CP Pulse Width	t _W	1.5	73	-	84	-	ns
		3.3	8.2	-	9.4	-	ns
		5	5.9	-	6.7	-	ns
Set-up Time	tsu	1.5	27	-	31	-	ns
		3.3	3.1	-	3.5	-	ns
		5	2.2	-	2.5	-	ns
Hold Time	t _H	1.5	27	-	31	-	ns
		3.3	3.1	-	3.5	-	ns
		5	2.2	-	2.5	-	ns
MR to CP Removal Time	t _{REM}	1.5	1	-	1	-	ns
		3.3	1	-	1	-	ns
		5	1	-	1	-	ns
ACT TYPES	•						
Max. Clock Frequency	f _{MAX}	5 (Note 10)	80	-	70	-	MHz
MR Pulse Width	t _W	5	3.9	-	4.5	-	ns
CP Pulse Width	t _W	5	6.2	-	7.1	-	ns
Set-up Time	tsu	5	2.2	-	2.5	-	ns
Hold Time	tH	5	2.6	-	3	-	ns
MR to CP Removal Time	t _{REM}	5	0	-	0	-	ns

Switching Specifications Input t_r , t_f = 3ns, C_L = 50pF (Worst Case)

			-40°C TO 85°C		-55°C TO 125°C				
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
AC TYPES									
Propagation Delay,	t _{PLH} , t _{PHL}	1.5	-	-	143	-	-	157	ns
CP to Qn		3.3 (Note 9)	4.5	-	15.9	4.4	-	17.5	ns
		5 (Note 10)	3.2	-	11.4	3.1	-	12.5	ns

Switching Specifications Input t_r , $t_f = 3ns$, $C_L = 50pF$ (Worst Case) (Continued)

			-40°C TO 85°C		-55				
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Propagation Delay,	t _{PLH} , t _{PHL}	1.5	-	-	158	-	-	174	ns
MR to Qn		3.3	5	-	17.7	4.9	-	19.5	ns
		5	3.6	-	12.6	3.5	-	13.9	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 11)	-	-	150	-	-	150	-	pF
ACT TYPES									
Propagation Delay, CP to Qn	t _{PLH} , t _{PHL}	5 (Note 10)	3.8	-	13.5	3.7	-	14.9	ns
Propagation Delay, MR to Qn	t _{PLH} , t _{PHL}	5	4.1	-	14.4	4	-	15.8	ns
Input Capacitance	C _I	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 11)	-	-	150	-	-	150	-	pF

- 8. Limits tested at 100%.
- 9. 3.3V Min at 3.6V, Max at 3V.
- 10. 5V Min at 5.5V, Max at 4.5V.
- 11. C_{PD} is used to determine the dynamic power consumption per device. $P_D = C_{PD} V_{CC}^2 f_i \Sigma (C_L V_{CC}^2 f_0) + V_{CC} \Delta I_{CC}$, where f_i = input frequency, f_0 = output frequency, C_L = output load capacitance, V_{CC} = supply voltage.

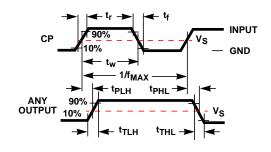


FIGURE 1.

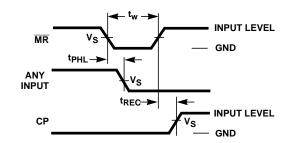


FIGURE 2.

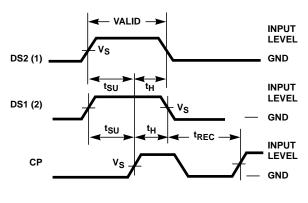


FIGURE 3.

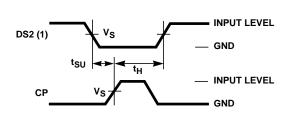
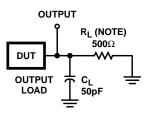


FIGURE 4.



NOTE: For AC Series Only: When V_{CC} = 1.5V, R_L = 1k Ω .

	AC	ACT
Input Level	V _{CC}	3V
Input Switching Voltage, V _S	0.5 V _{CC}	1.5V
Output Switching Voltage, V _S	0.5 V _{CC}	0.5 V _{CC}

FIGURE 5. PROPAGATION DELAY TIMES





22-Jul-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD54AC164F3A	ACTIVE	CDIP	J	14	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD54AC164F3A	Samples
CD54ACT164F3A	ACTIVE	CDIP	J	14	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD54ACT164F3A	Samples
CD74AC164E	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74AC164E	Samples
CD74AC164M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC164M	Samples
CD74AC164M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC164M	Samples
CD74AC164ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC164M	Samples
CD74ACT164E	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT164E	Samples
CD74ACT164EE4	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT164E	Samples
CD74ACT164M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT164M	Samples
CD74ACT164M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT164M	Samples
CD74ACT164M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT164M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet J\$709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".





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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54AC164, CD54AC164, CD74AC164, CD74AC164:

Catalog: CD74AC164, CD74ACT164

Military: CD54AC164, CD54ACT164

NOTE: Qualified Version Definitions:

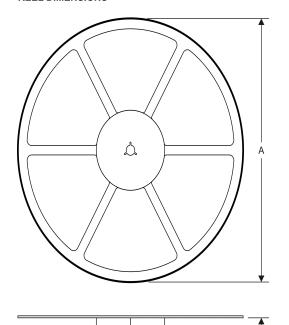
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

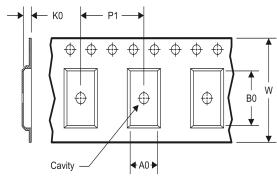
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TAPE AND REEL INFORMATION

REEL DIMENSIONS







A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC164M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74ACT164M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74AC164M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74ACT164M96	SOIC	D	14	2500	367.0	367.0	38.0

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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